NSN 5962-01-098-1840

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-098-1840

Body Length:
Between 1.150 inches and 1.220 inches
Body Width:
Between 0.480 inches and 0.520 inches
Body Height:
Between 0.070 inches and 0.130 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and programmable and programmed and w/storage and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
12 input
Case Outline Source And Designator:
Mo-015-ag joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Rom
Memory Capacity:
Unknown
Special Features:
Fast access time, 350 ns typical
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
<u> </u>

Demilitarization: Yes - demil/mli

NSN 5962-01-098-1840

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0